NSN 5962-01-161-3158

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View Online at https://aerobasegroup.com/nsn/5962-01-161-3158

Body Length:
Between 1.380 inches and 1.430 inches
Body Width:
Between 0.580 inches and 0.610 inches
Body Height:
Between 0.080 inches and 0.120 inches
Maximum Power Dissipation Rating:
600.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Radar system an/fps-117
Features Provided:
Hermetically sealed and burn in and w/enable and bipolar and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
18 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low leve
output
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

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